

SCES611G - OCTOBER 2004 - REVISED MAY 2010

SINGLE-SUPPLY VOLTAGE-LEVEL TRANSLATOR WITH NINE CONFIGURABLE GATE LOGIC FUNCTIONS

Check for Samples: SN74AUP1T57

FEATURES

- Available in the Texas Instruments NanoStar™ Packages
- Single-Supply Voltage Translator
- 1.8 V to 3.3 V (at $V_{CC} = 3.3$ V)
- 2.5 V to 3.3 V (at $V_{CC} = 3.3$ V) •
- 1.8 V to 2.5 V (at $V_{CC} = 2.5$ V)
- 3.3 V to 2.5 V (at $V_{CC} = 2.5$ V)
- **Nine Configurable Gate Logic Functions**
- Schmitt-Trigger Inputs Reject Input Noise and **Provide Better Output Signal Integrity**
- Ioff Supports Partial-Power-Down Mode With Low Leakage Current (0.5 µA)
- Very Low Static and Dynamic Power • Consumption
- Pb-Free Packages Available: SON (DRY or ٠ DSF), SOT-23 (DBV), SC-70 (DCK), and NanoStar WCSP
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Performance Tested Per JESD 22**
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Related Devices: SN74AUP1T58, SN74AUP1T97, and SN74AUP1T98

DESCRIPTION/ORDERING INFORMATION

AUP technology is the industry's lowest-power logic technology designed for use in battery-operated or battery backed-up equipment. The SN74AUP1T57 is designed for logic-level translation applications with input switching levels that accept 1.8-V LVCMOS signals, while operating from either a single 3.3-V or 2.5-V V_{CC} supply.

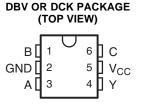
The wide V_{CC} range of 2.3 V to 3.6 V allows the possibility of battery voltage drop during system operation and ensures normal operation between this range.

Schmitt-trigger inputs (ΔV_T = 210 mV between positive and negative input transitions) offer improved noise immunity during switching transitions, which is especially useful on analog mixed-mode designs. Schmitt-trigger inputs reject input noise, ensure integrity of output signals, and allow for slow input signal transition.

The SN74AUP1T57 can be easily configured to perform a required gate function by connecting A, B, and C inputs to V_{CC} or ground (see Function Selection table). Up to nine commonly used logic gate functions can be performed.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoStar is a trademark of Texas Instruments.



DRY OR DSF PACKAGE (TOP VIEW)



YFP OR YZP PACKAGE (TOP VIEW)

1			1
В	(Á1) 1	6 (Áz)	С
GND	(B)¹ 2	5 (52)	V _{CC}
B GND A	(ćj) 3	4 (53)	Y



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 I_{off} is a feature that allows for powered-down conditions ($V_{CC} = 0$ V) and is important in portable and mobile applications. When $V_{CC} = 0$ V, signals in the range from 0 V to 3.6 V can be applied to the inputs and outputs of the device. No damage occurs to the device under these conditions.

The SN74AUP1T57 is designed with optimized current-drive capability of 4 mA to reduce line reflections, overshoot, and undershoot caused by high-drive outputs.

NanoStar package technology is a major breakthrough in IC packaging concepts, using the die as the package.

ORDERING INFORMATION⁽¹⁾

T _A	T _A PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1T57YZPR	TG_
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP	Reel of 3000	SN74AUP1T57YFPR	TG_
–40°C to 85°C	QFN – DRY	Reel of 5000	SN74AUP1T57DRYR	TG
	uQFN – DSF	Reel of 5000	SN74AUP1T57DSFR	TG
	SOT (SOT-23) – DBV	Reel of 3000	SN74AUP1T57DBVR	HT3_
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP1T57DCKR	TG_

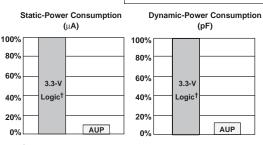
For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site. YFP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

LOGIC FUNCTION	FIGURE NO.
2-input AND gate	5
2-input NOR gate with both inputs inverted	5
2-input NAND gate with inverted input	6, 7
2-input OR gate with inverted input	6, 7
2-input AND gate with both inputs inverted	8
2-input NOR gate	8
2-input XNOR gate	9
Inverter	10
Noninverted buffer	11

FUNCTION SELECTION TABLE



† Single, dual, and triple gates



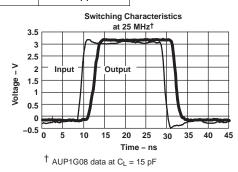


Figure 2. Excellent Signal Integrity

SN74AUP1T57



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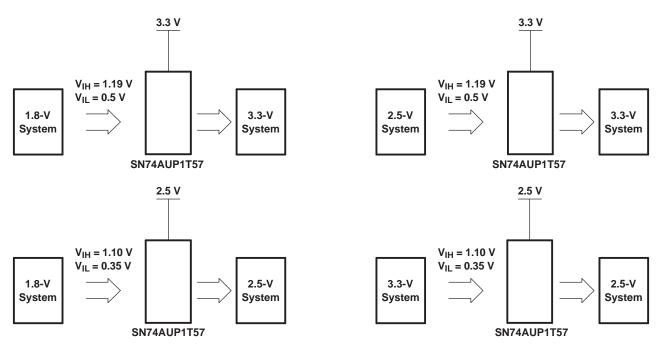


Figure 3. Possible Voltage-Translation Combinations

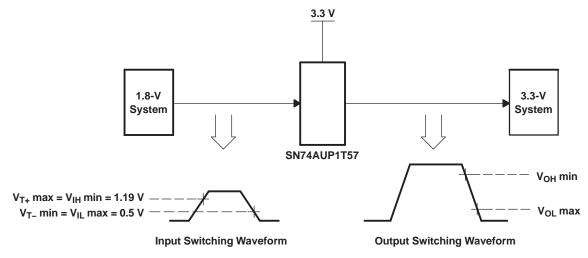
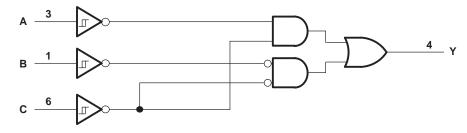


Figure 4. Switching Thresholds for 1.8-V to 3.3-V Translation

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	FUNCTION TABLE									
	INPUTS		OUTPUT							
С	В	Α	Y							
L	L	L	Н							
L	L	Н	L							
L	н	L	н							
L	н	н	L							
н	L	L	L							
Н	L	Н	L							
н	н	L	Н							
Н	Н	Н	Н							

LOGIC DIAGRAM (POSITIVE LOGIC)



LOGIC CONFIGURATIONS

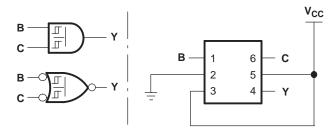


Figure 5. 08/14+2: 2-Input AND Gate 2-Input NOR Gate With Both Inputs Inverted

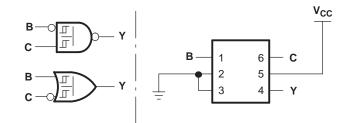


Figure 6. 14+00/14+32: 2-Input NAND Gate With Inverted B Input 2-Input OR Gate With Inverted Input



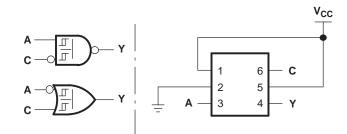


Figure 7. 14+00/14+32: 2-Input NAND Gate With Inverted C Input 2-Input OR Gate With Inverted Input

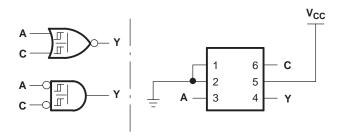


Figure 8. 02/14+08: 2-Input OR Gate 2-Input AND Gate With Both Inputs Inverted

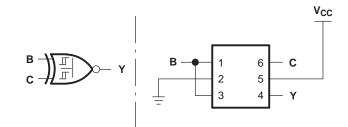
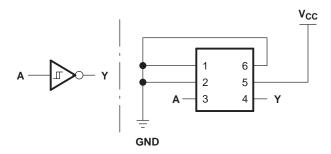
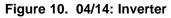


Figure 9. 86+04: 2-Input XNOR Gate







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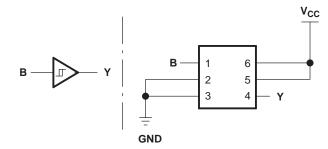


Figure 11. 17/34: Noninverted Buffer



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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range		-0.5	4.6	V	
VI	Input voltage range ⁽²⁾		-0.5	4.6	V	
Vo	Voltage range applied to any output in the high	gh-impedance or power-off state ⁽²⁾	-0.5	4.6	V	
Vo	Output voltage range in the high or low state	(2)	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA	
I _{OK}	Output clamp current	V _O < 0		-50	mA	
lo	Continuous output current			±20	mA	
	Continuous current through V_{CC} or GND			±50	mA	
		DBV package		165		
		DCK package		259		
0	Deckage thermal impedance (3)	DRY package		340	°C/W	
θ_{JA}	Package thermal impedance ⁽³⁾	DSF package		300 123		
		YFP package				
		YZP package		123		
T _{stg}	Storage temperature range		-65	150	°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2.3	3.6	V
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	V_{CC}	V
		$V_{CC} = 2.3 V$		-3.1	~ ^
IOH	High-level output current	$V_{CC} = 3 V$		-4	mA
		$V_{CC} = 2.3 V$		3.1	~ ^
OL	Low-level output current	$V_{CC} = 3 V$		4	mA
T _A	Operating free-air temperature		-40	85	°C

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report *Implications* of Slow or Floating CMOS Inputs, literature number SCBA004. SCES611G -OCTOBER 2004-REVISED MAY 2010

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ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	v _{cc}	T _A =	25°C	T _A = -40 to 85°	0°C C	UNIT	
			MIN	TYP MAX	MIN	MAX		
V _{T+}		2.3 V to 2.7 V	0.6	1.1	0.6	1.1		
Positive-going input threshold voltage		3 V to 3.6 V	0.75	1.16	0.75	1.19	V	
V _{T-}		2.3 V to 2.7 V	0.35	0.6	0.35	0.6		
Negative-going input threshold voltage		3 V to 3.6 V	0.5	0.85	0.5	0.85	V	
ΔV _T		2.3 V to 2.7 V	0.23	0.6	0.1	0.6		
Hysteresis $(V_{T+} - V_{T-})$		3 V to 3.6 V	0.25	0.56	0.15	0.56	V	
V _{OH}	I _{OH} = -20 μA	2.3 V to 3.6 V	$V_{CC} - 0.1$		V _{CC} - 0.1		V	
	I _{OH} = -2.3 mA	2.3 V	2.05		1.97			
	I _{OH} = -3.1 mA	2.3 V	1.9		1.85			
	I _{OH} = -2.7 mA	3 V	2.72		2.67			
	$I_{OH} = -4 \text{ mA}$	5 V	2.6		2.55			
	I _{OL} = 20 μA	2.3 V to 3.6 V		0.1		0.1	.33 .45 V	
	I _{OL} = 2.3 mA	2.3 V		0.31		0.33		
V _{OL}	I _{OL} = 3.1 mA	2.5 V		0.44		0.45		
	I _{OL} = 2.7 mA	3 V		0.31		0.33		
	I _{OL} = 4 mA	5 V		0.44		0.45		
II All inputs	$V_I = 3.6 V \text{ or GND}$	0 V to 3.6 V		0.1		0.5	μA	
l _{off}	V_I or $V_O = 0$ V to 3.6 V	0 V		0.1		0.5	μA	
ΔI _{off}	$V_I \text{ or } V_O = 3.6 \text{ V}$	0 V to 0.2 V		0.2		0.5	μA	
I _{cc}	$V_{I} = 3.6 \text{ V or GND}, I_{O} = 0$	2.3 V to 3.6 V		0.5		0.9	μA	
	One input at 0.3 V or 1.1 V, Other inputs at 0 or V _{CC} , $I_O = 0$	2.3 V to 2.7 V				4	μA	
ΔI _{CC}	One input at 0.45 V or 1.2 V, Other inputs at 0 or V_{CC} , $I_{O} = 0$	3 V to 3.6 V				12	μΑ	
C _i	$V_I = V_{CC}$ or GND	3.3 V		1.5			pF	
Co	$V_{O} = V_{CC}$ or GND	3.3 V		3			pF	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$, $V_I = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER		TO (OUTPUT)	CL	т,	ק = 25°C		T _A = to 85	40°C 5°C	UNIT	
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX		
	5 pF	1.8	2.3	2.9	0.5	6.8				
		Y	Y	10 pF	2.3	2.8	3.4	1	7.9	
t _{pd}	A, B, or C		15 pF	2.6	3.1	3.8	1	8.7	ns	
			30 pF	3.8	4.4	5.1	1.5	10.8		

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$, $V_I = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO	CL	Т	ק = 25°C		T _A = to 85	40°C 5°C	UNIT
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	
			5 pF	1.8	2.3	3.1	0.5	6	
		X	10 pF	2.2	2.8	3.5	1	7.1	
t _{pd} A, B, or C	A, B, or C	Y	15 pF	2.6	3.2	5.2	1	7.9	ns
			30 pF	3.7	4.4	5.2	1.5	10	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$, $V_I = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	FROM (INPUT)	TO (OUTPUT)			T _A = 25°C	40°C 5°C	UNIT			
	(INPUT)	(OUTPUT)	-	MIN	TYP	MAX	MIN	MAX		
	A, B, or C	A, B, or C Y		5 pF	2	2.7	3.5	0.5	5.5	
			10 pF	2.4	3.1	3.9	1	6.5		
t _{pd} A, B, or C			15 pF	2.8	3.5	4.3	1	7.4	ns	
			30 pF	4	4.7	5.5	1.5	9.5		

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_I = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO (OUTPUT)	CL	Т	ק = 25°C		T _A = to 85	40°C 5°C	UNIT
	(INPUT)		MIN	TYP	MAX	MIN	MAX		
	5 pF	1.6	2	2.5	0.5	8			
		V	10 pF	2	2.4	2.9	1	8.5	
^t pd	A, B, or C	Ŷ	15 pF	2.3	2.8	3.3	1	9.1	ns
			30 pF	3.4	3.9	4.4	1.5	9.8	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_1 = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see Figure 12)

	PARAMETER	FROM	TO (OUTPUT)	CL 5 pF 10 pF 15 pF 30 pF	Т	∖ = 25°C		T _A = to 85	40°C 5°C	UNIT	
		(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX		
		A, B, or C Y			5 pF	1.6	1.9	2.4	0.5	5.3	
			Y		V	10 pF	2	2.3	2.7	1	6.1
	τ _{pd}			15 pF	2.3	2.7	3.1	1	6.8	ns	
				30 pF	3.4	3.8	4.2	1.5	8.5		



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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_1 = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO	CL	Т	∖ = 25°C		T _A = to 85	UNIT			
	(INPUT)	(OUTPUT)	_	MIN	TYP	MAX	MIN	MAX			
t _{pd}		Y	5 pF	1.6	2.1	2.7	0.5	4.7			
			Y	Y	10 pF	2	2.4	3	1	5.7	
	A, B, or C				ř	15 pF	2.3	2.7	3.3	1	6.2
			30 pF	3.4	3.8	4.4	1.5	7.8			

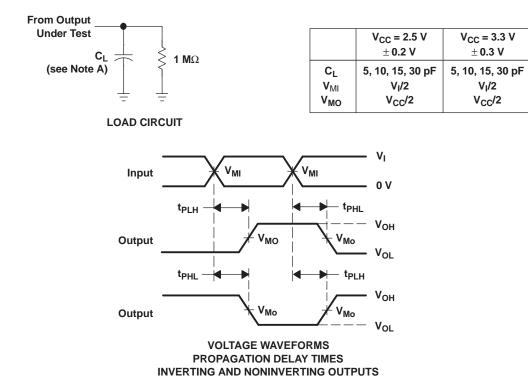
OPERATING CHARACTERISTICS

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V_{CC} = 2.5 V	V_{CC} = 3.3 V	UNIT	
	FARAMETER	TEST CONDITIONS	TYP	TYP	UNIT	
C _{pd}	Power dissipation capacitance	f = 10 MHz	4	5	pF	



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PARAMETER MEASUREMENT INFORMATION

- NOTES: A. C_L includes probe and jig capacitance.
 - B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , slew rate \geq 1 V/ns.
 - C. The outputs are measured one at a time, with one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 12. Load Circuit and Voltage Waveforms



PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
SN74AUP1T57DBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HT3F, HT3R)	Samples
SN74AUP1T57DBVT	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HT3F, HT3R)	Samples
SN74AUP1T57DCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TGF, TGR)	Samples
SN74AUP1T57DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	TG	Samples
SN74AUP1T57DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	TG	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

10-Sep-2024

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

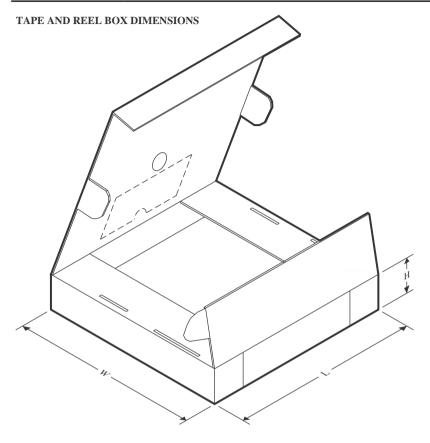


*All dimensions are nominal	-,											
Device	-	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1T57DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1T57DBVT	SOT-23	DBV	6	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1T57DCKR	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
SN74AUP1T57DRYR	SON	DRY	6	5000	180.0	8.4	1.25	1.6	0.7	4.0	8.0	Q1
SN74AUP1T57DSFR	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2



PACKAGE MATERIALS INFORMATION

13-Oct-2024



*All dimensions are nominal	
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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1T57DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74AUP1T57DBVT	SOT-23	DBV	6	250	202.0	201.0	28.0
SN74AUP1T57DCKR	SC70	DCK	6	3000	202.0	201.0	28.0
SN74AUP1T57DRYR	SON	DRY	6	5000	202.0	201.0	28.0
SN74AUP1T57DSFR	SON	DSF	6	5000	210.0	185.0	35.0

DBV0006A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



DBV0006A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DBV0006A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



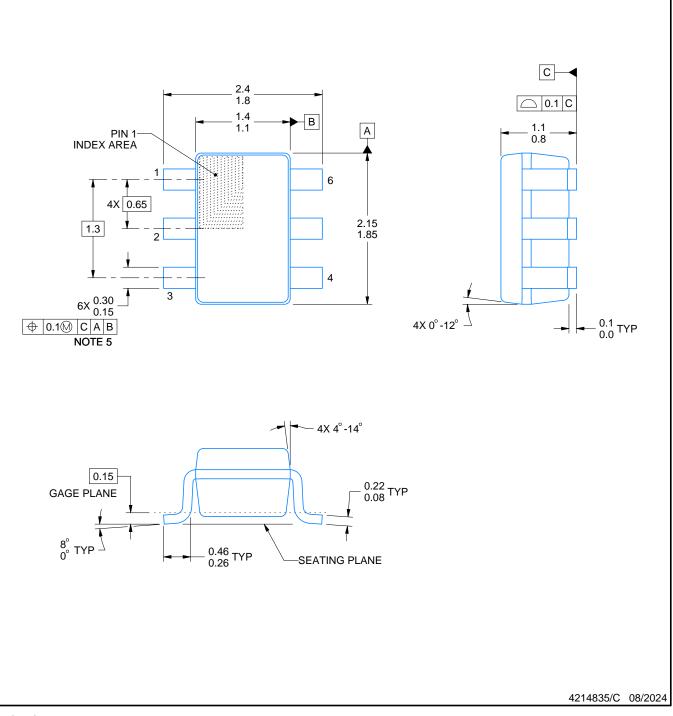
DCK0006A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing an integration of a constraint of the minimeters. Any dimensions in parentnesis are for reference only. Dimensioning and to per ASME Y14.5M.
 This drawing is subject to change without notice.
 Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 Falls within JEDEC MO-203 variation AB.

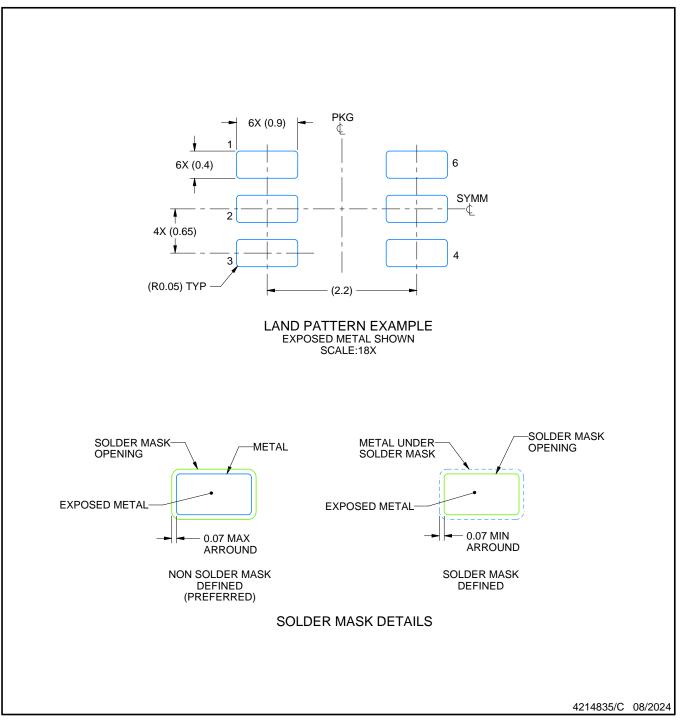


DCK0006A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

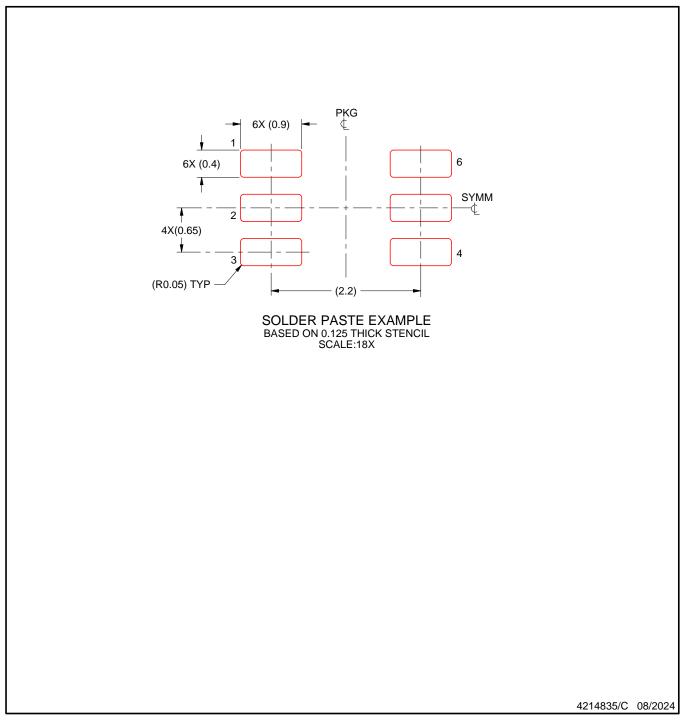


DCK0006A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Board assembly site may have different recommendations for stencil design.



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

GENERIC PACKAGE VIEW

USON - 0.6 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4207181/G

DRY0006A



PACKAGE OUTLINE

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.



DRY0006A

EXAMPLE BOARD LAYOUT

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).



DRY0006A

EXAMPLE STENCIL DESIGN

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DSF0006A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing Per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration MO-287, variation X2AAF.



DSF0006A

EXAMPLE BOARD LAYOUT

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



DSF0006A

EXAMPLE STENCIL DESIGN

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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